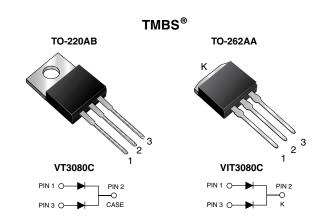




Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$



| PRIMARY CHARACTERISTICS | | | | | |
|---|----------|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _{RRM} | 80 V | | | | |
| I _{FSM} | 150 A | | | | |
| V _F at I _F = 15 A | 0.65 V | | | | |
| T _J max. | 150 °C | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

High efficiency operation
COMPLIANT
HALOGEN

 Solder bath temperature 275 °C max. 10 s, per JESD 22-B106

- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reserve battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|-------------------------|-----------------------------------|---------------|----------|------|--|
| PARAMETER | | SYMBOL | VT3080C | VIT3080C | UNIT | |
| Maximum repetitive peak reverse voltage | nge V _{RRM} 80 | | 0 | V | | |
| Maximum average forward rectified current (fig. 1) | per device | | 30 | | А | |
| | per diode | I _{F(AV)} | 15 | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | I _{FSM} | 150 | | А | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs | |
| Operating junction and storage temperature range | | T _J , T _{STG} | - 55 to + 150 | | °C | |

VT3080C, VIT3080C

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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|------------------------|--------------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | = 7.5 A T _A = 25 °C | V _F ⁽¹⁾ | 0.52 | - | . V | |
| | I _F = 7.5 A | | | 0.58 | - | | |
| | I _F = 15 A | | | 0.75 | 0.82 | | |
| | I _F = 5 A | T _A = 125 °C | | 0.46 | - | | |
| | I _F = 7.5 A | | | 0.52 | - | | |
| | I _F = 15 A | | | 0.65 | 0.70 | | |
| Reverse current per diode | V _R = 80 V | T _A = 25 °C | I _R ⁽²⁾ | 30 | 700 | μΑ | |
| | v _R = 00 v | T _A = 125 °C | | 20 | 35 | mA | |

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|--------------------|---------|----------|------|
| PARAMETER | | SYMBOL | VT3080C | VIT3080C | UNIT |
| Typical thermal resistance | per diode | р | 2.5 | | °C/W |
| | per device | - R _{θJC} | 2.0 | | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | VT3080C-M3/4W | 1.89 | 4W | 50/tube | Tube | |
| TO-262AA | VIT3080C-M3/4W | 1.46 | 4W | 50/tube | Tube | |
| TO-220AB ⁽¹⁾ | VT3080CHM3/4W | 1.89 | 4W | 50/tube | Tube | |
| TO-262AA ⁽¹⁾ | VIT3080CHM3/4W | 1.46 | 4W | 50/tube | Tube | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

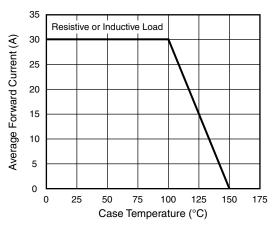


Fig. 1 - Maximum Forward Current Derating Curve

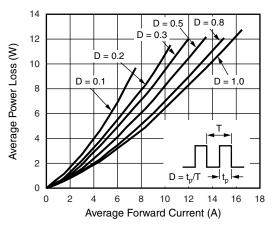


Fig. 2 - Forward Power Dissipation Characteristics

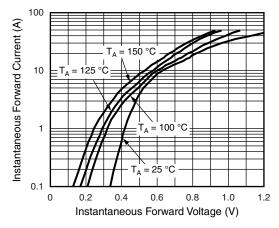


Fig. 3 - Typical Instantaneous Forward Characteristics

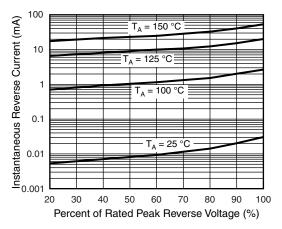


Fig. 4 - Typical Reverse Characteristics

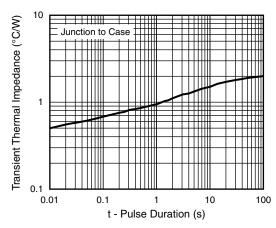


Fig. 5 - Typical Transient Thermal Impedance

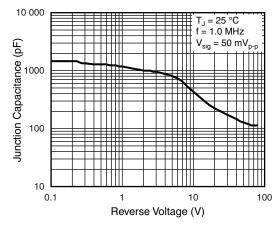


Fig. 6 - Typical Junction Capacitance

VT3080C, VIT3080C

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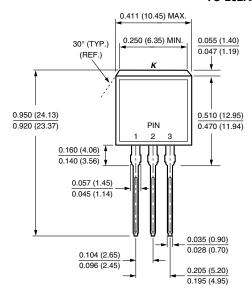
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

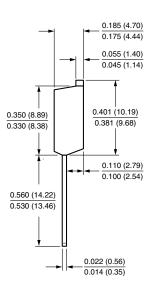
TO-220AB 0.415 (10.54) MAX. 0.185 (4.70) 0.370 (9.40) 0.154 (3.91) 0.175 (4.44) 0.360 (9.14) 0.148 (3.74) 0.055 (1.39) 0.113 (2.87) 0.045 (1.14) 0.103 (2.62) 0.145 (3.68) 0.135 (3.43) 0.603 (15.32) 0.635 (16.13) 0.625 (15.87) 0.573 (14.55) PIN 0.350 (8.89) 0.330 (8.38) 0.160 (4.06) 1.148 (29.16) 0.140 (3.56) 1.118 (28.40) 0.110 (2.79) 0.100 (2.54) 0.057 (1.45) 0.045 (1.14) 0.560 (14.22) 0.530 (13.46) 0.105 (2.67) 0.095 (2.41) 0.035 (0.90) 0.104 (2.65) 0.028 (0.70) 0.022 (0.56) 0.205 (5.20) 0.096 (2.45)

TO-262AA

0.195 (4.95)

0.014 (0.36)









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